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INFORMATION DISCLOSURE STATEMENT							
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APPLICANTS Makoto IIDA et al.							
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Examiner Initials	Cite No.	Document Number	Date	Name			
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EXAMINER				DATE CONSIDERED			
/G. Nagesh Rao/ (10/22/2009)				10/22/2009			
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							

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ALL REFERENCES CONSIDERED EXCEPT WHERE LINED THROUGH. /G.N.R.